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Highly Efficient and Exceptionally Durable CO_2 Photoreduction to Methanol over Freestanding Defective Single-Unit-Cell Bismuth Vanadate Layers

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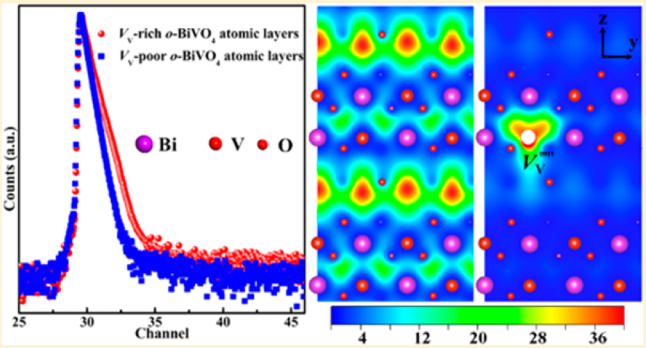
Supporting Information

ABSTRACT: Unearthing an ideal model for disclosing the role of defect sites in solar CO_2 reduction remains a great challenge. Here, freestanding gram-scale single-unit-cell *o*-$BiVO_4$ layers are successfully synthesized for the first time. Positron annihilation spectrometry and X-ray fluorescence unveil their distinct vanadium vacancy concentrations. Density functional calculations reveal that the introduction of vanadium vacancies brings a new defect level and higher hole concentration near Fermi level, resulting in increased photoabsorption and superior electronic conductivity. The higher surface photovoltage intensity of single-unit-cell *o*-$BiVO_4$ layers with rich vanadium vacancies ensures their higher carriers separation efficiency, further confirmed by the increased carriers lifetime from 74.5 to 143.6 ns revealed by time-resolved fluorescence emission decay spectra. As a result, single-unit-cell *o*-$BiVO_4$ layers with rich vanadium vacancies exhibit a high methanol formation rate up to 398.3 μmol g^{-1} h^{-1} and an apparent quantum efficiency of 5.96% at 350 nm, much larger than that of single-unit-cell *o*-$BiVO_4$ layers with poor vanadium vacancies, and also the former's catalytic activity proceeds without deactivation even after 96 h. This highly efficient and spectrally stable CO_2 photoconversion performances hold great promise for practical implementation of solar fuel production.



INTRODUCTION

Worldwide consumption of finite fossil fuels not only accelerates their depletion but also results in overproduction of atmospheric CO_2 concentration, both of which will restrict social development and endanger human survival.[1−6] In this regard, conversion of waste CO_2 into energy-rich fuels by artificial photosynthesis seems to be one of the most promising pathways for simultaneously solving the energy and environmental problems.[6−9] Nowadays, numerous semiconductors such as TiO_2, Bi_2WO_6 and Zn_2GeO_4 have been reported for CO_2 photoreduction to form valuable chemicals,[10−13] while their low CO_2 conversion efficiency or serious photocorrosion process greatly impede their practical implementation. Currently, several strategies have been proposed to solve these problems,[9,14,15] in which the introduction of defects on the photocatalysts could greatly influence the photoreduction performances.[7] However, to date, atomic-level insight into defects in photocatalytic CO_2 conversion is still an open query, which could be primarily ascribed to the following reason. In the previously fabricated photocatalysts with large crystal size, the defects usually distribute on the interior of catalysts rather than on the surface, and thus they could not effectively involve the photocatalytic reactions. In view of disclosing the atomic-level correlation between defect sites and CO_2 photoconversion, it is obligatory to develop a material model with mainstream of defects dispensing on the surface.

Herein, we initially built an ideal material model of atomically thin layers that possess relatively single active site, and hence we deliberately create lots of defects on the surface of atomically thin layers, enabling them to behave roughly two kinds of active sites, i.e., surface sites and defect sites. The atomic thickness and two-dimensional structure make the number of these active sites comparable with their total atoms,[16] thus providing new opportunities to disclose the correlation between defect sites and solar CO_2 reduction. Taking the nontoxic and stable orthorhombic-$BiVO_4$ (*o*-$BiVO_4$) as an example,[17] vanadium(V)-defective *o*-$BiVO_4$ single-unit-cell layer and perfect *o*-$BiVO_4$ single-unit-cell layer slabs are built and hence density functional theory (DFT)

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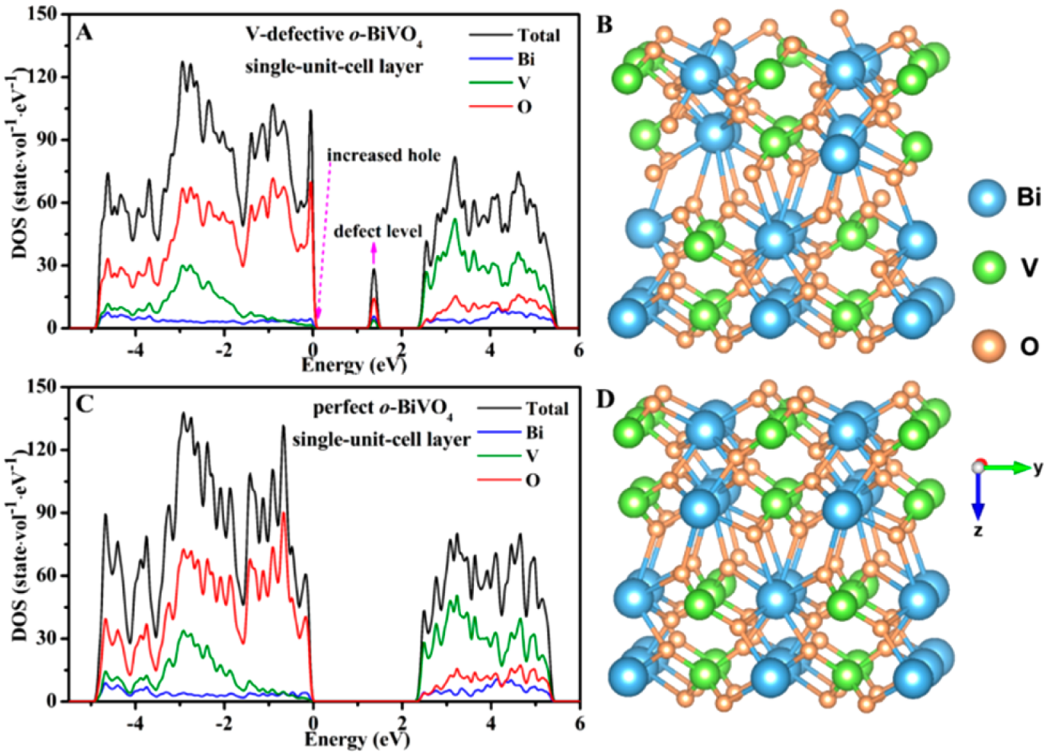

Figure 1. DFT calculations. Calculated density of states of (A) V-defective *o*-$BiVO_4$ single-unit-cell layer slab and (C) perfect *o*-$BiVO_4$ single-unit-cell layer slab along the [001] orientation. Crystal structure of (B) V-defective *o*-$BiVO_4$ single-unit-cell layer slab and (D) perfect *o*-$BiVO_4$ single-unit-cell layer slab along the [001] orientation.

calculations are performed to investigate the role of vanadium-defects on the electronic structure. Of note, Figure 1 clearly reveals that the presence of vanadium vacancies results in the appearance of a new defect level, which makes the electrons to be easily excited into the conduction band under solar irradiation, thus ensuring higher photoconversion efficiency. Moreover, one can also see that the V-defective *o*-$BiVO_4$ single-unit-cell layer exhibits higher hole concentration at the valence band edge in comparison with the perfect single-unit-cell layer, which infers the higher transition probability of photoexcited electrons to the conduction band under solar light illumination and hence improves the CO_2 photoreduction activity. With all of these advantages, it is rather imperative to fabricate *o*-$BiVO_4$ single-unit-cell layers with/without vanadium vacancies. However, since its discovery in nature as the orthorhombic mineral pucherite in 1973,[17] the artificial synthesis of *o*-$BiVO_4$ has never been realized due to the absence of a chemically synthetic strategy, let alone the controllable synthesis of its atomic layers with desirable vanadium vacancies.

RESULTS AND DISCUSSION

To accomplish the above grant challenge, we highlight a lamellar hybrid intermediate strategy for gram-scale synthesizing V_v-rich and V_v-poor *o*-$BiVO_4$ atomic layers with one-unit-cell thickness, representing the first artificial synthetic case after a delay of more than 40 years. Note that cetyltrimethylammonium bromide (CTAB) played a crucial role in the formation of atomically thin layers, in which it helps to form an artificial lamellar $BiCl_4^-$-CTA^+ hybrid precursors via the self-assembly process (Figure 2A),[18] confirmed by the corresponding small-angle XRD pattern in Figure S1. With the addition of Na_3VO_4 followed by hydrothermal treatment, the VO_4^{3-} ions would react with the Bi^{3+} in the lamellar $BiCl_4^-$-CTA^+ hybrid precursors and simultaneously the formed $BiVO_4$-based lamellar structures gradually self-exfoliated into *o*-$BiVO_4$ atomic layers. Taking the products obtained at 160 °C for 3 h as an example, their XRD pattern in Figure 2C could be readily indexed to the orthorhombic-$BiVO_4$ (JCPDS No. 85−1730), further demonstrated by the corresponding Raman spectra in Figure S2A.[19] Interestingly, compared with the relative intensity shown in the standard pattern in Figure 2C, the relatively strong 002 and 004 diffraction peaks indicated that the as-synthesized products possessed a [001] orientation. In addition, their XPS spectra and elemental mapping images in Figure S2B−D and S3 demonstrated the formation of pure $BiVO_4$, further verified by the corresponding IR spectrum in Figure S4,[19] which suggested the absence of impurities such as CTAB and Cl^- on the surface of the as-obtained *o*-$BiVO_4$ sample. Moreover, sheet-like structures of *o*-$BiVO_4$ are depicted by TEM image in Figure 2B, while the atomic force microscopic (AFM) image and the corresponding height profiles in Figure 2D-E revealed their average 1.28 nm thickness, which fairly agreed with the 1.2 nm thickness of a unit cell along the [001] direction. More importantly, the weight of the final *o*-$BiVO_4$ ultrathin sheets are 2.184 g at one time synthesis (Figure S5), which would be beneficial for their large-scale applications. Therefore, all the above results demonstrated the gram-scale synthesis of *o*-$BiVO_4$ atomic layers with a thickness of a unit cell, providing new opportunities for fabricating large-area ultrathin nanodevices.

To detect the types and quantities of defects in the synthetic *o*-$BiVO_4$ atomic layers, positron annihilation spectrometry (PAS) was performed and the results were shown in Figure 3, Figure S9 and Tables 1 and 2. As revealed by the positron lifetime spectra in Figure 3A and the corresponding derived lifetime parameters in Table 1, the *o*-$BiVO_4$ atomic layers

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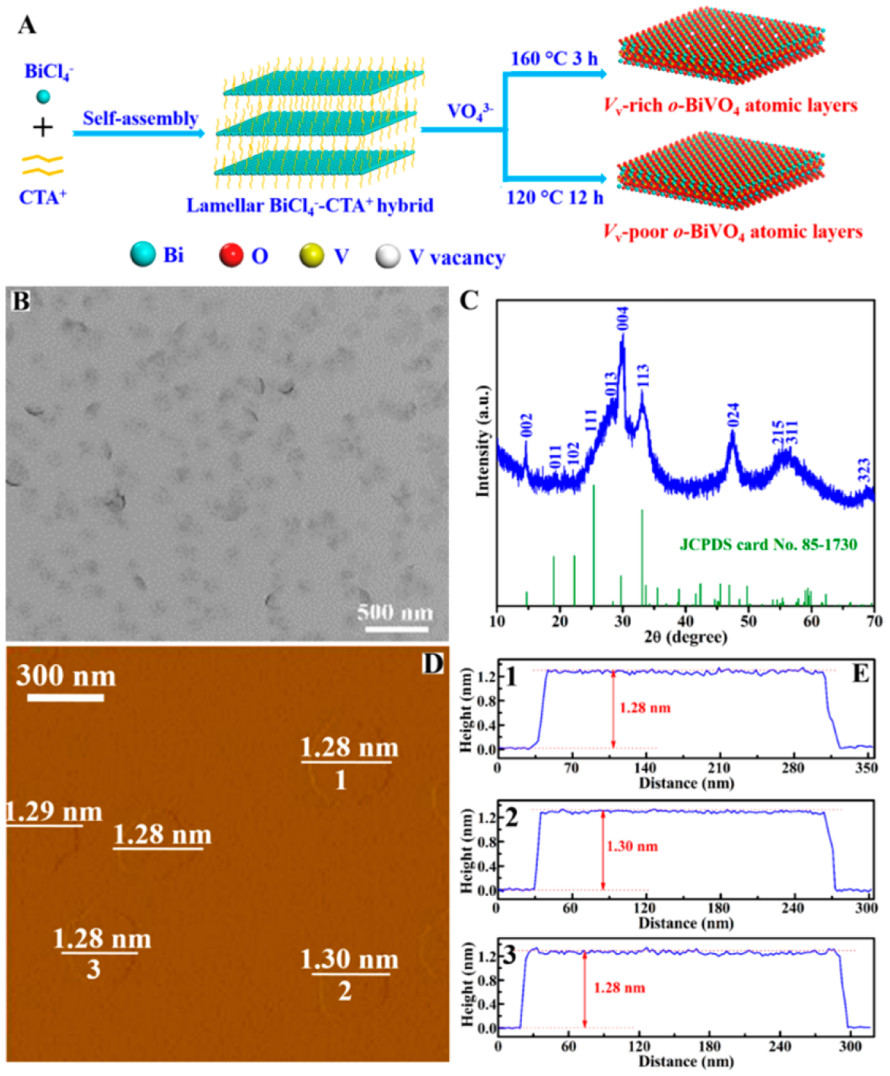

Figure 2. Scheme and characterizations for the synthetic *o*-$BiVO_4$ atomic layers. (A) Scheme for the gram-scale synthesis of the V_v-rich and V_v-poor *o*-$BiVO_4$ atomic layers. Characterizations for the V_v-rich *o*-$BiVO_4$ atomic layers with one-unit-cell thickness: (B) TEM image, (C) XRD pattern, (D) AFM image and (E) the corresponding height profiles; the numbers from 1 to 3 in (D) correspond to the numbers from 1 to 3 in (E).

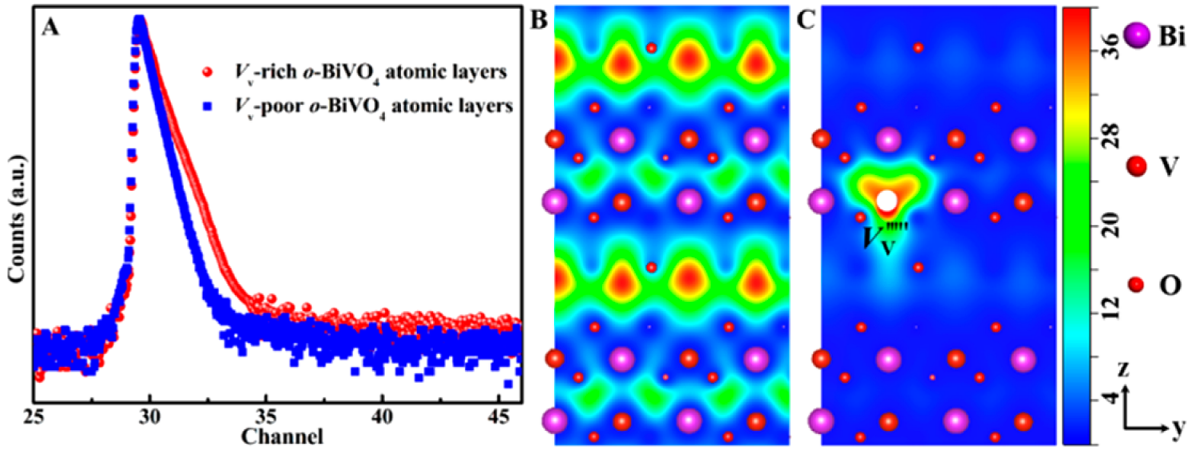

Figure 3. Defects characterization for the V_v-rich and V_v-poor *o*-BiVO4 atomic layers. (A) Positron lifetime spectrum. (B,C) Schematic representation of trapped positrons.

exhibited three lifetime components, in which the two longer life components (τ_2, τ_3) could be ascribed to the large voids and the interface present in the samples.[20] Also, the shortest one (τ_1, around 200 ps) for the two samples could be attributed to positron annihilation trapped at vanadium vacancy of V_v'''', according to the theoretically calculated positron lifetime values

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Table 1. Positron Lifetime Parameters of *o*-$BiVO_4$ Atomic Layers[a]

sample	τ_1 (ps)	τ_2 (ps)	τ_3 (ns)	I_1 (%)	I_2 (%)	I_3 (%)
V_V-poor *o*-$BiVO_4$ atomic layers	200.1 ± 20	366.7 ± 3.9	2.57 ± 0.3	12.4 ± 2.9	87.7 ± 2.9	0.06 ± 0.03
V_V-rich *o*-$BiV0_4$ atomic layers	208.9 ± 18	387.5 ± 2.6	2.84 ± 1.3	27.5 ± 5.7	72.3 ± 5.7	0.2 ± 0.06

[a] τ_1–τ_3 correspond to different positron lifetime in defective *o*-$BiVO_4$ atomic layers that have been detected in positron annihilation measurement. I_1–I_3 are the corresponding relative intensities.

Table 2. Calculated Positron Lifetime Values of $BiVO_4$

defect	bulk	V_V''''	V_{Bi}'''	$V_O^{\cdot\cdot}$
lifetime (ps)	193	198	236	178

in Table 2, which implied the presence of V_V'''' vacancy in these two samples. In addition to the lifetime of the positron, the relative intensity of positron lifetime also provided more information on the concentration of the defects, in which Table 1 quantified the higher vanadium vacancy concentration in the sample obtained at 160 °C for 3 h in comparison with that yielded at 120 °C for 12 h (Figure S6–S8). Importantly, as revealed by the X-ray fluorescence (XRF) in Figure S10, the element ratio of V and Bi for the V_V-rich and V_V-poor *o*-$BiVO_4$ atomic layers were 0.914 and 0.976, respectively, which suggested that the two samples possessed different amount of V vacancies, fairly consisting with that of the PAS measurements. This strongly demonstrated that the reaction temper-

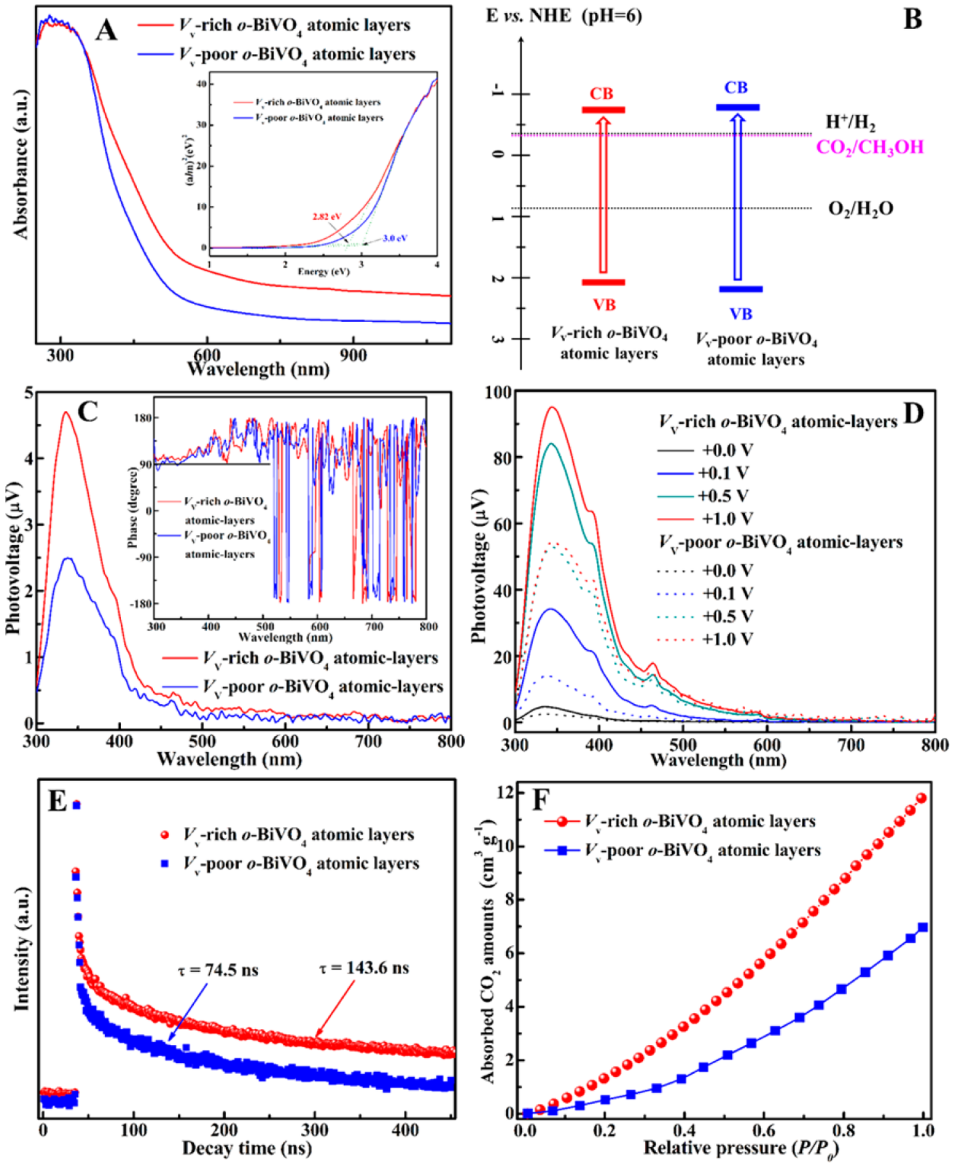

Figure 4. Photo- and electrical properties for V_V-rich and V_V-poor *o*-$BiVO_4$ atomic layers. (A) UV–vis diffuse reflectance spectra, (B) band positions based on the bandgaps and valence band spectra, (C) surface photovoltage spectra and (inset) corresponding phase spectra, (D) the field-induced surface photovoltage spectra under different external electric fields, (E) time-resolved fluorescence emission decay spectra, (F) CO_2 adsorption isotherms.

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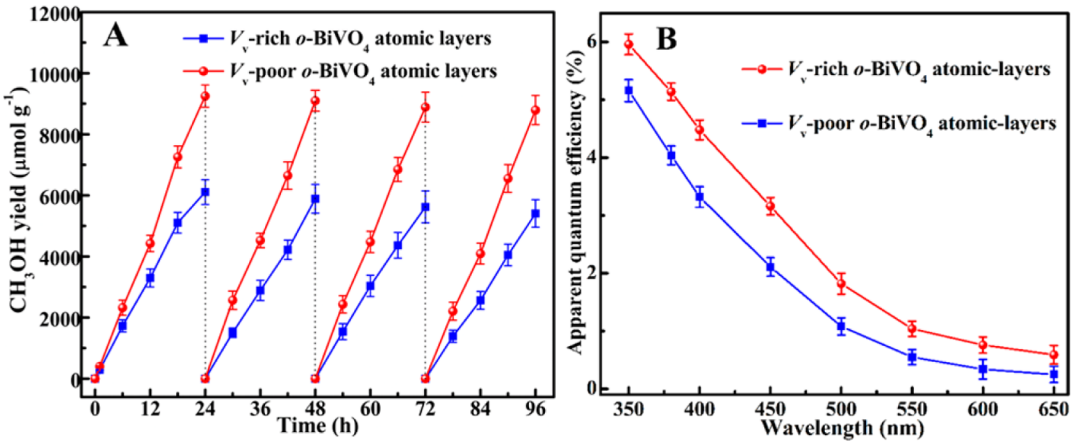

Figure 5. Photocatalytic methanol evolution under 300 W Xe lamp irradiation for V_v-rich and V_v-poor o-$BiVO_4$ atomic layers. (A) Photostability test and (B) apparent quantum yields. The error bars in A and B represent the standard deviations of three independent measurements of the same sample.

ature and time could help to tune the concentration of vanadium vacancy, hence providing two ideal models to study the vanadium vacancy-photocatalysis relationship.

Of note, though most monoclinic $BiVO_4$ like WO_3 is known to be inactive to reduce water or CO_2,[21,22] the ultrathin thickness down to single-unit-cell layer as well as the structural defects would endow the synthetic o-$BiVO_4$ atomic layers with suitable electronic band structure to reduce CO_2 into methanol and simultaneously oxidize H_2O into O_2. To determine the positions of band edges relative to redox potentials of reactions, we further performed XPS valence band (VB) spectra to measure their VB position (Figure S11).[23] As shown in Figure S11, the VB maximum of V_v-poor o-$BiVO_4$ atomic layers is 2.48 eV, more positive than that of V_v-rich o-$BiVO_4$ atomic layers.[22,24] On the basis of the band gaps in Figure 4A and the measured XPS valence band positions in Figure S11, the approximate band-edge positions of both the V_v-rich and V_v-poor o-$BiVO_4$ atomic layers was drawn versus a normal hydrogen electrode (NHE, pH = 6). As can be seen in Figure 4B, both the samples possessed the abilities to get both CO_2 reduction and O_2 evolution occurring at the same time.[22,24]

As is well-known, electron−hole separation efficiency of photocatalyst is a very important factor for determining the photocatalytic activity. In this case, surface photovoltage spectroscopy (SPV) was employed to reveal the dynamic behaviors of the photogenerated charge carriers in the synthetic V_v-rich and V_v-poor o-$BiVO_4$ atomic layers.[25] Both the V_v-rich and V_v-poor o-$BiVO_4$ atomic layers showed a strong SPV response band in the range of 300−520 nm, which corresponded to band-to-band transition.[26] The increased SPV intensity for the V_v-rich o-$BiVO_4$ atomic layers indicated that introducing vanadium vacancies was beneficial for the separation of photogenerated electron−hole pairs in o-$BiVO_4$ atomic layers. Moreover, as shown in the inset of Figure 4C, the phase spectra for both the V_v-rich and V_v-poor o-$BiVO_4$ atomic layers showed the similar statistic kinetic characteristics in the range of 300−520 nm, and in the nonresponse range of 520−800 nm, the phase value signals were stochastic. The phase angles in the response region were in the range of +90° to +180°, indicating that photogenerated electrons and holes moved toward the surface and bulk of p-type o-$BiVO_4$ atomic layers, respectively.[26,27] Hence, the photoinduced electrons accumulated at surface of the o-$BiVO_4$ atomic layers would be beneficial for the activation and reduction of the surface adsorbed CO_2 molecule by a one-electron transfer. Furthermore, in the CO_2 photoreduction process, the adsorbed CO_2 and H_2O molecules were the two important reactive resources and their polarization effect on the o-$BiVO_4$ atomic layers would strongly affect the electron affinity as well as the surface reduction reactions. To investigate the influence of polarization effect in solar CO_2 reduction performances, we further performed the field induced surface photovoltage spectra (FISPS), in which the effect of applied voltage in the FISPS measurements was similar to the polarization effect of adsorbed CO_2 and H_2O molecules.[26,28] As revealed in Figure 4D, one can clearly see that the SPV response intensities for both the V_v-rich and V_v-poor o-$BiVO_4$ atomic layers gradually increased with the increasing positive electric field, indicating that the direction of external field was consistent with that of the built-in electric field in o-$BiVO_4$ atomic layers, and hence further demonstrated the p-type conduction character of both the synthetic o-$BiVO_4$ atomic layers. Also, under the applied electric field, SPV response also appeared in the visible light range of 520−600 nm, which corresponded to the sub-band gap transition. More importantly, at the same external voltage, the V_v-rich o-$BiVO_4$ atomic layers exhibited much higher SPV intensities in the range of 300−600 nm than the V_v-poor o-$BiVO_4$ atomic layers, suggesting that the abundant vanadium vacancies ensured stronger polarization effect and hence favored much efficient separation efficiency of photoinduced charge carriers. Of note, as revealed by the CO_2 adsorption isotherms and contact angle measurements in Figure 4F and Figure S12, the V_v-rich o-$BiVO_4$ atomic layers possessed higher CO_2 adsorption capacity and stronger surface hydrophilicity relative to the V_v-poor o-$BiVO_4$ atomic layers, thanks to the former's higher vanadium vacancy concentration. Thus, the CO_2 and H_2O molecules would show stronger polarization effect on the V_v-rich o-$BiVO_4$ atomic layers, and hence allow for much improved photoinduced charge carrier separation efficiency. To verify the above viewpoint, time-resolved fluorescence emission decay spectra for the two samples were performed and shown in Figure 4E. The decay kinetics for V_v-rich o-$BiVO_4$ atomic layers, in which their respective average fluorescence lifetimes were 143.6 and 74.5 ns. The significantly increased carriers lifetime confirmed that the presence of

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vanadium vacancies could effectively facilitate the separation of photogenerated electron and hole.[9]

Taking the several advantages demonstrated above, the V_v-rich *o*-$BiVO_4$ atomic layers would show remarkably promoted CO_2 photoreduction properties. To verify this viewpoint, the solar CO_2 reduction experiments were carried out in water under a 300 W Xe lamp with a standard AM 1.5G filter, and the predominant reaction product analyzed by gas chromatography (GC) was methanol, along with a small amount of H_2 as well as trace amount of ethanol (Figure S13). Control experiments demonstrated that there was no detectable methanol generation in the dark or in the absence of CO_2, verifying that the methanol formation was derived from CO_2 reduction driven by solar light irradiation. To further disclose the origin of methanol, we further performed the $^{13}CO_2$ labeling experiment. As shown in Figure S14, a signal corresponded to the proton was observed in the ^1H NMR spectrum (Figure S14A), while a strong signal attributed to $^{13}CH_3OH$ was observed at 49.7 ppm in the ^{13}C NMR spectrum (Figure S14B).[29,30] These results strongly demonstrated that the methanol was in fact derived from CO_2. Figure 5A revealed that the V_v-rich *o*-$BiVO_4$ atomic layers exhibited the methanol formation rate of 398.3 μmol g^{-1} h^{-1}, roughly 1.4 times higher than that of the V_v-poor *o*-$BiVO_4$ atomic layers, which strongly verified the crucial role of V_v'''' vacancies in improving the photocatalytic activity. In addition, the higher vanadium vacancy amount for the V_v-rich *o*-$BiVO_4$ atomic layers also accounted for their higher apparent quantum efficiency, reaching a maximum of 5.96% at 350 nm (Figure 5B). Interestingly, the V_v-rich *o*-$BiVO_4$ atomic layers exhibited nearly the same BET surface area as that of the V_v-poor *o*-$BiVO_4$ atomic layers (Figure S15), which cannot account for the former's higher catalytic activity. This indicated that the enhanced catalytic performance of the V_v-rich *o*-$BiVO_4$ atomic layers was not due to the BET surface area, but instead the increased concentration of vanadium vacancies, which favored much higher activity toward methanol production. Moreover, the experimental results demonstrated that both the V_v-rich and V_v-poor *o*-$BiVO_4$ atomic layers could also realize the water oxidation into O_2 (Figure S16), while the rate ratio for O_2 and CH_3OH was about 1.5, which fairly agreed with the theoretical results. That is to say, the number of electron consumed for methanol, H_2 and ethanol generation was almost equal to that of electrons produced during O_2 evolution, demonstrating that the photogenerated electrons and holes simultaneously participated the respective reduction and oxidation reactions. Notably, the XRD patterns and Raman spectra in Figure S17 strongly demonstrated the phase of the V_v-rich and V_v-poor *o*-$BiVO_4$ atomic layers does not occur any obvious variation after 96 h photoreduction test, verifying their favorable photostability. More importantly, for the V_v-rich *o*-$BiVO_4$ atomic layers, their methanol yield gradually increased with the photolysis time increased up to 96 h, without showing any obvious loss of photocatalytic activity, which confirmed their superior photostability (Figure 5A). Contrastingly, the methanol yield for the V_v-poor *o*-$BiVO_4$ atomic layers increased slowly with the increasing solar irradiation, which further implied that the presence of abundant V_v'''' vacancies ensured much better photostability, hence giving prospective signs for practical solar fuels production.

CONCLUSION

In conclusion, atomic layers with tunable defect concentrations were first put forward as an excellent platform to disclose the atomic-level correlation between defect sites and CO_2 photoconversion. As an example, freestanding V_v-rich and V_v-poor *o*-$BiVO_4$ atomic layers with one-unit-cell thickness on gram-scale were first successfully synthesized via a lamellar hybrid intermediate strategy. Positron annihilation spectrometry and X-ray fluorescence demonstrated the distinct vanadium vacancy concentration in these fabricated *o*-$BiVO_4$ atomic layers. DFT calculation revealed that the presence of vanadium vacancies resulted in the appearance of a new defect level, which allowed for increased photoabsorption confirmed by the UV−vis diffuse reflectance spectra as well as higher apparent quantum efficiency. In addition, surface photovoltage spectroscopy disclosed that larger vanadium vacancy amount ensured higher carriers separation efficiency, confirmed by the time-resolved fluorescence spectra. The carriers lifetime for V_v-rich *o*-$BiVO_4$ atomic layers was up to 143.6 ns, roughly 2 times longer than that of V_v-poor *o*-$BiVO_4$ atomic layers. Benefiting from the above several advantages, the V_v-rich *o*-$BiVO_4$ atomic layers exhibited the high methanol formation rate up to 398.3 μmol g^{-1} h^{-1}, roughly 1.4 times higher than that of the V_v-poor *o*-$BiVO_4$ atomic layers. Also, the catalytic activity for V_v-rich *o*-$BiVO_4$ atomic layers did not show any obvious deactivation even after 96 h-period photocatalysis, while the V_v-poor *o*-$BiVO_4$ atomic layers displayed relatively poor photostability. Accordingly, this present study not only develops a facile strategy for gram-scale fabrication of *o*-$BiVO_4$ atomic layers, but also theoretically/experimentally demonstrates the crucial role of defect sites in fully optimizing CO_2 photoreduction efficiency, opening up new possibilities for efficient and stable solar fuel production.

EXPERIMENTAL SECTION

Synthesis of V_v-rich *o*-$BiVO_4$ Atomic Layers. In a typical scalable procedure, 2.21 g $BiCl_3$ and 1.05 g CTAB was added into 60 mL ethylene glycol. After vigorous stirring for 40 min, 2.80 g $Na_3VO_4 \cdot 12H_2O$ was also added into the reacted system and then the mixture was transferred into a 100 mL Teflon-lined autoclave, sealed and heated at 160 °C for 3 h. The system was then allowed to cool down to room temperature naturally, the final product was collected by centrifuging the mixture, washed with ethanol and water for many times, and then dried in vacuum overnight for further characterization. More importantly, the yield of the products was only dependent on the volume of the Teflon-lined autoclave.

Synthesis of V_v-Poor *o*-$BiVO_4$ Atomic Layers. In a typical scalable procedure, 2.21 g $BiCl_3$ and 1.05 g CTAB was added into 60 mL ethylene glycol. After vigorous stirring for 40 min, 2.80 g $Na_3VO_4 \cdot 12H_2O$ was also added into the reacted system and then the mixture was transferred into a 100 mL Teflon-lined autoclave, sealed and heated at 120 °C for 12 h. The system was then allowed to cool down to room temperature naturally, the final product was collected by centrifuging the mixture, washed with ethanol and water for many times, and then dried in vacuum overnight for further characterization. More importantly, the yield of the products was only dependent on the volume of the Teflon-lined autoclave.

Characterization. Transmission electron microscopy (TEM) images and high-resolution TEM image were performed by using a JEOL-2010 TEM with an acceleration voltage of 200 kV. XRD patterns were recorded by using a Philips X'Pert Pro Super diffractometer with Cu Kα radiation (λ = 1.54178 Å). X-ray photoelectron spectra (XPS) were acquired on an ESCALAB MKII with Mg Kα (hυ = 1253.6 eV) as the excitation source. The binding energies obtained in the XPS spectral analysis were corrected for specimen charging by referencing C 1s to 284.8 eV. Room-temperature UV−vis diffuse reflectance spectroscopy (DRS) were recorded on a PerkinElmer Lambda 950 UV−vis−NIR spectrophotometer. Raman spectra were detected by a RenishawRM3000 Micro-

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Raman system. The Fourier transform infrared (FT-IR) spectra were acquired on a NICOLET FT-IR spectrometer in a KBr tablets, scanning from 4000 to 400 cm^{-1} at room temperature. Elemental analysis for the products was performed on an XRF-1800. The decay time spectra were recorded on a spectrophotometer (FLS920, Edinburgh Instruments Ltd.). Decay curves for the two *o*-$BiVO_4$ atomic layers were recorded with excitation at 400 nm and emission at 525 nm. The surface photovoltage spectroscopy (SPV) and Field-induced surface photovoltage spectroscopy (FISPS) measurements were carried out on a homemade apparatus, which was constituted by a source of monochromatic light with a light chopper, and a lock-in amplifier. The measurement was performed in air atmosphere and room temperature. Atomic force microscopy (AFM) study in the present work was performed as follows: Mica sheet was initially fixed on the surface of nickel substance and then the up surface of the Mica sheet was stripped by tape. When the up surface of Mica sheet was flat uniformly, 50 μL colloidal dispersion (2 mg sample was uniformly dispersed into 10 mL ethanol or water under ultrasonication) was dropped by Micro syringe on the flat surface of Mica sheet and then dried in air naturally for further AFM characterization (Veeco DI Nanoscope MultiMode V system).

Density Functional Theory Calculations. were performed using the Vienna ab initio simulation package (VASP) with projector-augmented wave (PAW) pseudopotentials and the generalized gradient approximation in the parametrization of Perdew, Burke and Enzerhof for the exchange-correlation functional.[31−34] Bi 5d6s6p electrons, V 3s3p3d4s electrons, and O 2s2p electrons were treated as the valence electrons in the PAW potentials. The plane-wave energy cutoff, 400 eV, was determined by the VASP PAW potential of O. All atoms fully relaxed during structural relaxation until the force on each atom was smaller than 0.01 eV/Å. The lattice parameters of the optimized orthorhombic phase $BiVO_4$ are a = 5.393 Å, b = 5.093 Å, and c = 12.088 Å, in consistent with the experimental values of a = 5.328 Å, b = 5.052 Å, and c = 12.003 Å. The 2D $BiVO_4$ thin film was model by a 2 × 2 × 1 cell with a vacuum region over 13 Å containing 16 Bi, 16 V, and 64 O atoms. We used a 7 × 7 × 1 k-point mesh including the Γ point for the Brillouin Zone integration.

Photocatalytic CO_2 Reduction Measurement. In the photocatalytic conversion of CO_2, $BiVO_4$ powder (0.2 g) was suspended in 160 mL water with magnetic stirring, and high purity CO_2 gas was continuously bubbled through the solution at the rate of 0.5 mL min^{-1}. A 300 W Xe lamp (PLS-SXE300/300UV, Trusttech Co., Ltd. Beijing) with a standard AM1.5 filter, outputting the light density of about 100 mW/cm^2, was used as the light source. The photocatalytic CO_2 reduction experiments were conducted in a closed vessel at 0 °C, and the suspensions were irradiated through the quartz window. Prior to irradiation, CO_2 gas was bubbled to the solution for 30 min to expel the dissolved oxygen in the vessel. The vessel temperature was kept at about 0 °C by recirculating cooling water system to increase the solubility of CO_2. The products in the solution were qualitatively identified by gas chromatography (SP6800A with GDX-502 columns) equipped with a flame ionization detector (FID), and the outlet gases were sampled through a sampling value and analyzed by gas chromatography (SP6800A with TDX-01 columns) equipped with thermal conductivity detector (TCD). All peaks were checked with their corresponding standards, and each experiment was repeated at least 5 times in parallel to obtain an average value. The wavelength-dependent apparent quantum yields (AQY) was measured under the same photocatalytic reaction condition, except for the incident light wavelength. The solar fuels (methanol) yields of 10 h photoreaction under different monochromatic light wavelengths (350, 380, 400, 450, 500, 550, 600, and 650 nm) were measured. All the fwhm of these wavelengths were 10 nm. The temperatures of the solutions were controlled at 273 ± 0.2 K by recirculating cooling water system during irradiation. The incident light intensity was determined using a Silicon-UV enhanced actinometer. The wavelength-dependent AQY was calculated as the ratio between the number of photogenerated electrons consumption and the number of incident photons, by taking into account the fact that 6 electrons are required according to the stoichiometry of the reaction: $CO_2 + 2H_2O \rightarrow CH_3OH + 3/2O_2$. All the experiments were repeated at least 5 times in parallel to obtain an average value.

Positron Annihilation Measurement. The positron lifetime measurements were carried out with a fast−fast coincidence system with a time resolution of ∼240 ps full width at half-maximum. Each spectrum was collected with a total count of 1×10^6. A 30 μCi source of ^{22}Na was sandwiched between two identical $BiVO_4$ samples. All the samples were measured at least 3 times in parallel to obtain an average value. To obtain the positron lifetimes, the ATSUP method and the GGA (Generalized Gradient Approximation) form of the enhancement factor were chosen.[35,36] The electron density and the positron crystalline Coulomb potential were constructed by the nonself-consistent superposition of free atom electron density and Coulomb potential in the absence of the positron. The model of 3 × 3 × 2 supercells were used for Positron lifetime calculations of 2D $BiVO_4$ with unrelaxed structure vacancy.

The specific fitting parameters for both V_v-poor and V_v-rich *o*-$BiVO_4$ atomic layers are also shown in the Figure S9. According to the LTv9 program, the primitive spectra can be decomposed to five components. Two of them come from source contribution including the annihilation in source itself (NaCl) and the Kapton film which are used to cover the source. The line in dark yellow and purple are attributed to these two components obtained by measuring a single crystal silicon. The left three components indicated by dark gray, blue, and black lines are attributed to the samples, which correspond to around 200 ps, 370 ps, and more than 2 ns, respectively. Moreover, the fitting residuals are also shown in the bottom of the picture (olive lines). The uniformity of these scatter plots imply the rationality of this fitting.

■ ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/jacs.6b11263.

Positron Annihilation measurement, yields of various products, ^{13}C labeling experiment, details of XRD, XPS, XRF, Raman, FT-IR, BET surface area, Elemental mapping images, XPS valence band spectrum, contact angles, TEM and AFM image, as well as supplementary demonstration of gram-scale synthesis (PDF)

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Notes

The authors declare no competing financial interest.

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